

Dual General Purpose Transistors

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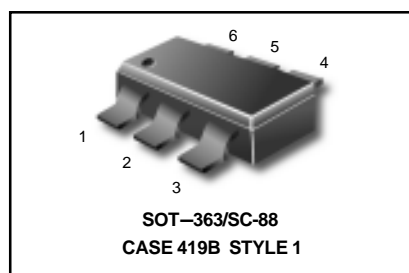
NPN/PNP Duals (Complimentary)

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363/SC-88 which is designed for low power surface mount applications.

• Device Marking:

- LBC846BPDW1T1 = BB
- LBC847BPDW1T1 = 13F
- LBC847CPDW1T1 = 13G
- LBC848BPDW1T1 = 13K
- LBC848CPDW1T1 = 13L

LBC846BPDW1T1
LBC847BPDW1T1
LBC847CPDW1T1
LBC848BPDW1T1
LBC848CPDW1T1

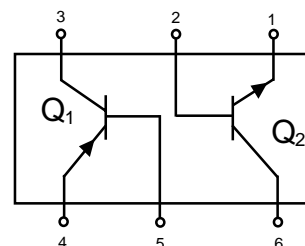


MAXIMUM RATINGS – NPN

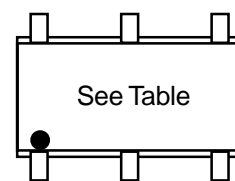
Rating	Symbol	LBC846	LBC847	LBC848	Unit
Collector-Emitter Voltage	V_{CEO}	65	45	30	V
Collector-Base Voltage	V_{CBO}	80	50	30	V
Emitter-Base Voltage	V_{EBO}	6.0	6.0	5.0	V
Collector Current I_C Continuous	I_C	100	100	100	mA

MAXIMUM RATINGS – PNP

Rating	Symbol	LBC846	LBC847	LBC848	Unit
Collector-Emitter Voltage	V_{CEO}	-65	-45	-30	V
Collector-Base Voltage	V_{CBO}	-80	-50	-30	V
Emitter-Base Voltage	V_{EBO}	-5.0	-5.0	-5.0	V
Collector Current I_C Continuous	I_C	-100	-100	-100	mA



DEVICE MARKING



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR-5 Board (1) $T_A = 25^\circ\text{C}$ Derate Above 25°C	P_D	380 250	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	328	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

1. FR-5 = 1.0 x 0.75 x 0.062 in

ORDERING INFORMATION

Device	Package	Shipping
LBC846BPDW1T1	SOT-363	3000 Units/Reel
LBC847BPDW1T1	SOT-363	3000 Units/Reel
LBC847CPDW1T1	SOT-363	3000 Units/Reel
LBC848BPDW1T1	SOT-363	3000 Units/Reel
LBC848CPDW1T1	SOT-363	3000 Units/Reel

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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ELECTRICAL CHARACTERISTICS (NPN) ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = 10\text{ mA}$)	$V_{(BR)CEO}$	65 45 30	—	—	V
Collector–Emitter Breakdown Voltage ($I_C = 10\ \mu\text{A}$, $V_{EB} = 0$)	$V_{(BR)CES}$	80 50 30	—	—	V
Collector–Base Breakdown Voltage ($I_C = 10\ \mu\text{A}$)	$V_{(BR)CBO}$	80 50 30	—	—	V
Emitter–Base Breakdown Voltage ($I_E = 1.0\ \mu\text{A}$)	$V_{(BR)EBO}$	6.0 6.0 5.0	—	—	V
Collector Cutoff Current ($V_{CB} = 30\text{ V}$) ($V_{CB} = 30\text{ V}$, $T_A = 150^\circ\text{C}$)	I_{CBO}	—	—	15 5.0	nA μA

ON CHARACTERISTICS

DC Current Gain ($I_C = 10\ \mu\text{A}$, $V_{CE} = 5.0\text{ V}$)	h_{FE}	— —	150 270	—	—
($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$)		200 420	290 520	475 800	
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)	$V_{CE(sat)}$	— —	—	0.25 0.6	V
Base–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)	$V_{BE(sat)}$	— —	0.7 0.9	—	V
Base–Emitter Voltage ($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$) ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}$)	$V_{BE(on)}$	580 —	660 —	700 770	mV

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = 10\text{ V}$, $f = 1.0\text{ MHz}$)	C_{obo}	—	—	4.5	pF
Noise Figure ($I_C = 0.2\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$)	NF	—	—	10	dB

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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ELECTRICAL CHARACTERISTICS (PNP) ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = -10\text{ mA}$) LBC846 Series LBC847 Series LBC848 Series	$V_{(BR)CEO}$	-65 -45 -30	—	—	V
Collector–Emitter Breakdown Voltage ($I_C = -10\ \mu\text{A}$, $V_{EB} = 0$) LBC846 Series LBC847 Series LBC848 Series	$V_{(BR)CES}$	-80 -50 -30	—	—	V
Collector–Base Breakdown Voltage ($I_C = -10\ \mu\text{A}$) LBC846 Series LBC847 Series LBC848 Series	$V_{(BR)CBO}$	-80 -50 -30	—	—	V
Emitter–Base Breakdown Voltage ($I_E = -1.0\ \mu\text{A}$) LBC846 Series LBC847 Series LBC848 Series	$V_{(BR)EBO}$	-5.0 -5.0 -5.0	—	—	V
Collector Cutoff Current ($V_{CB} = -30\text{ V}$) ($V_{CB} = -30\text{ V}$, $T_A = 150^\circ\text{C}$)	I_{CBO}	— —	—	-15 -4.0	nA μA

ON CHARACTERISTICS

DC Current Gain ($I_C = -10\ \mu\text{A}$, $V_{CE} = -5.0\text{ V}$) LBC846B, LBC847B, LBC848B LBC847C, LBC848C ($I_C = -2.0\text{ mA}$, $V_{CE} = -5.0\text{ V}$) LBC846B, LBC847B, LBC848B LBC847C, LBC848C	h_{FE}	— — 200 420	150 270 290 520	— — 475 800	—
Collector–Emitter Saturation Voltage ($I_C = -10\text{ mA}$, $I_B = -0.5\text{ mA}$) ($I_C = -100\text{ mA}$, $I_B = -5.0\text{ mA}$)	$V_{CE(sat)}$	— —	—	-0.3 -0.65	V
Base–Emitter Saturation Voltage ($I_C = -10\text{ mA}$, $I_B = -0.5\text{ mA}$) ($I_C = -100\text{ mA}$, $I_B = -5.0\text{ mA}$)	$V_{BE(sat)}$	— —	-0.7 -0.9	—	V
Base–Emitter On Voltage ($I_C = -2.0\text{ mA}$, $V_{CE} = -5.0\text{ V}$) ($I_C = -10\text{ mA}$, $V_{CE} = -5.0\text{ V}$)	$V_{BE(on)}$	-0.6 —	—	-0.75 -0.82	V

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = -10\text{ mA}$, $V_{CE} = -5.0\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = -10\text{ V}$, $f = 1.0\text{ MHz}$)	C_{ob}	—	—	4.5	pF
Noise Figure ($I_C = -0.2\text{ mA}$, $V_{CE} = -5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$)	NF	—	—	10	dB

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

TYPICAL NPN CHARACTERISTICS – LBC846

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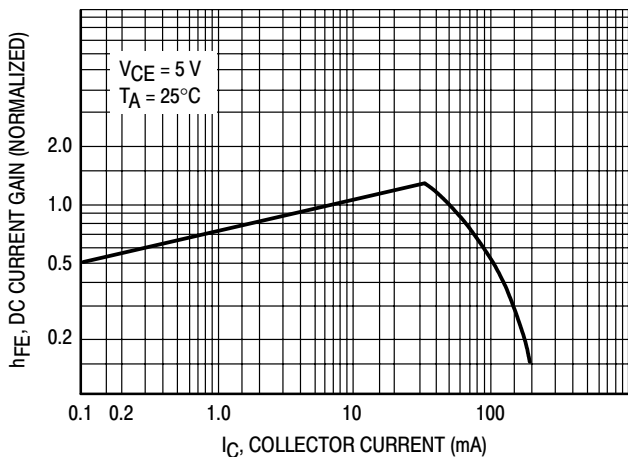


Figure 1. DC Current Gain

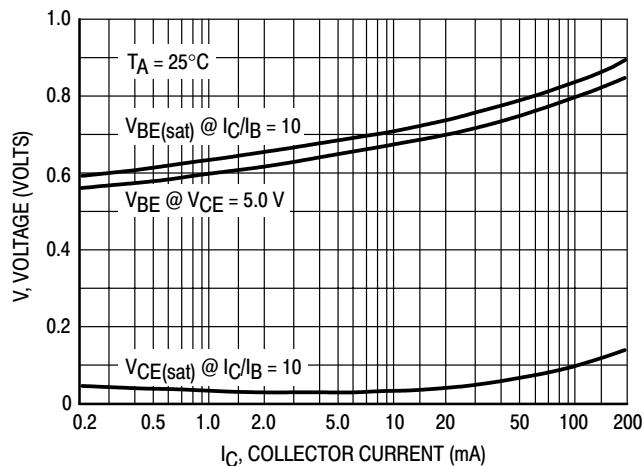


Figure 2. "On" Voltage

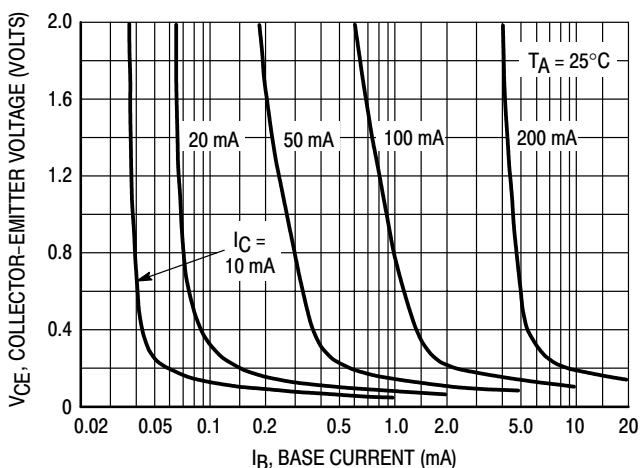


Figure 3. Collector Saturation Region

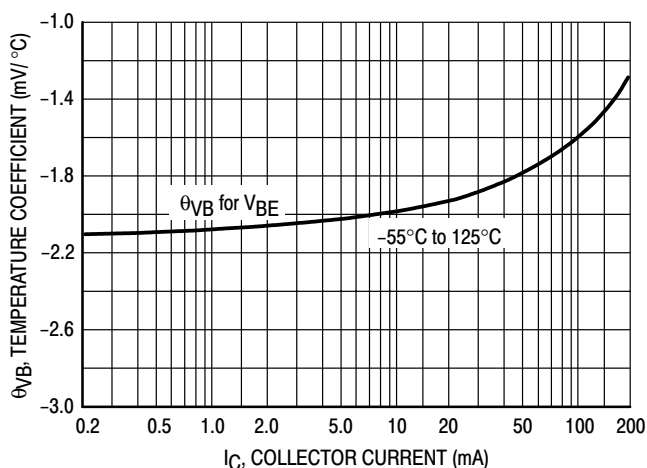


Figure 4. Base-Emitter Temperature Coefficient

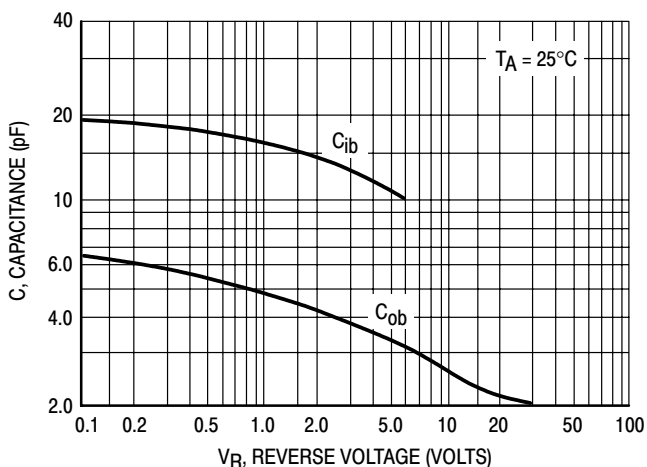


Figure 5. Capacitance

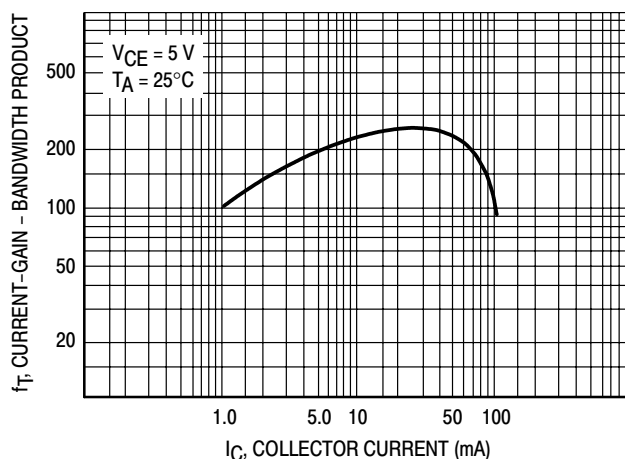


Figure 6. Current-Gain - Bandwidth Product

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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TYPICAL PNP CHARACTERISTICS — LBC846

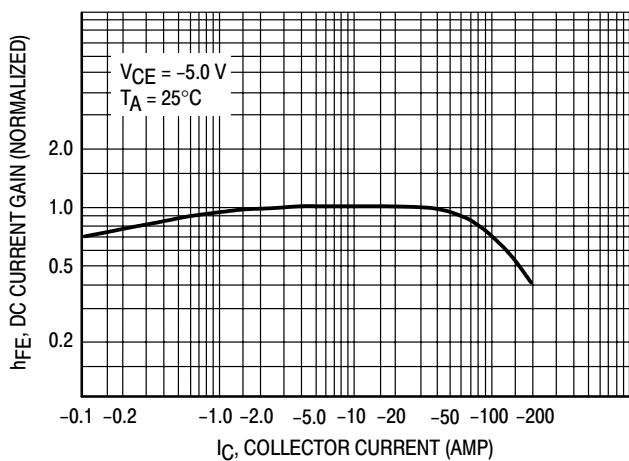


Figure 7. DC Current Gain

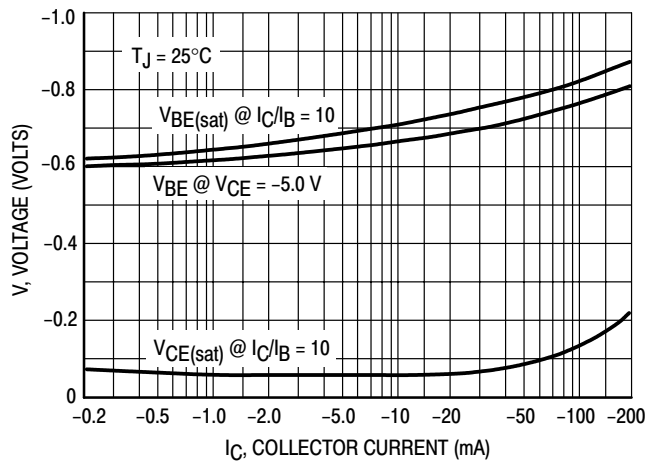


Figure 8. "On" Voltage

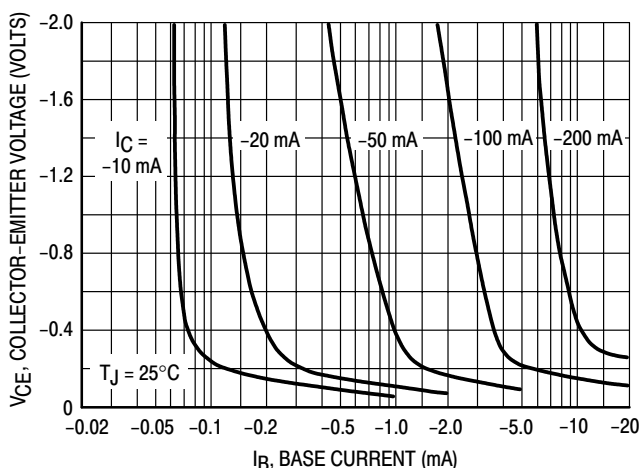


Figure 9. Collector Saturation Region

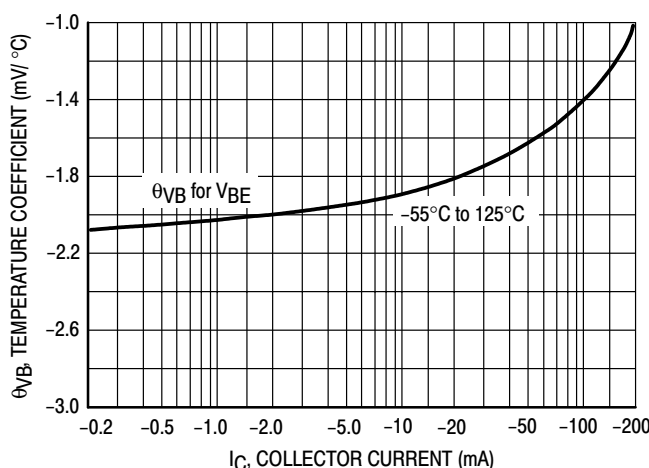


Figure 10. Base-Emitter Temperature Coefficient

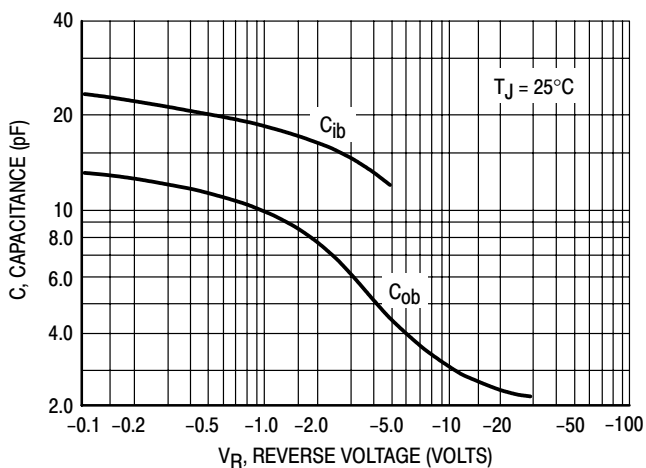


Figure 11. Capacitance

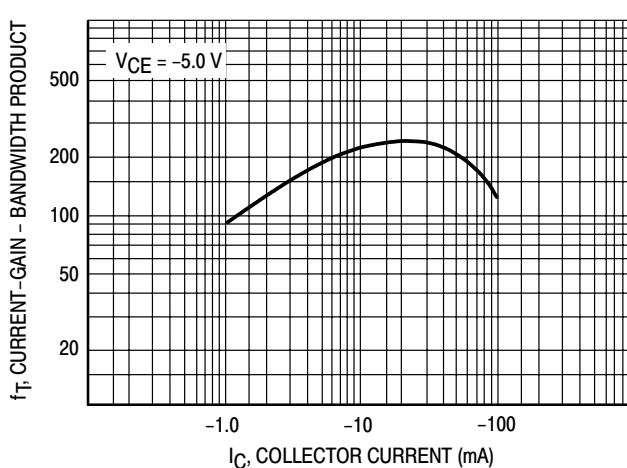


Figure 12. Current-Gain - Bandwidth Product

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

TYPICAL NPN CHARACTERISTICS – LBC847 SERIES & LBC848 SERIES

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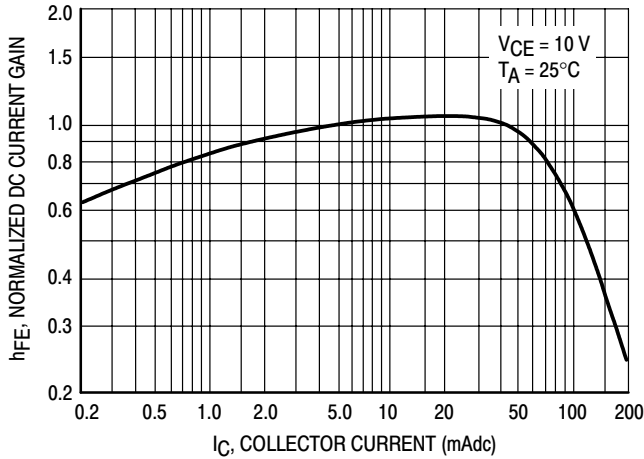


Figure 13. Normalized DC Current Gain

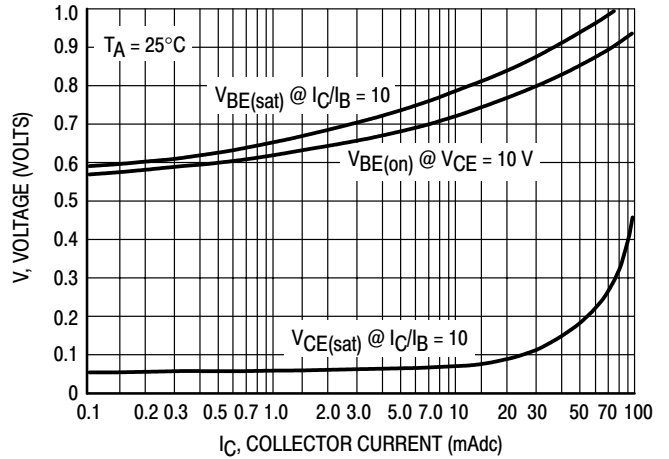


Figure 14. "Saturation" and "On" Voltages

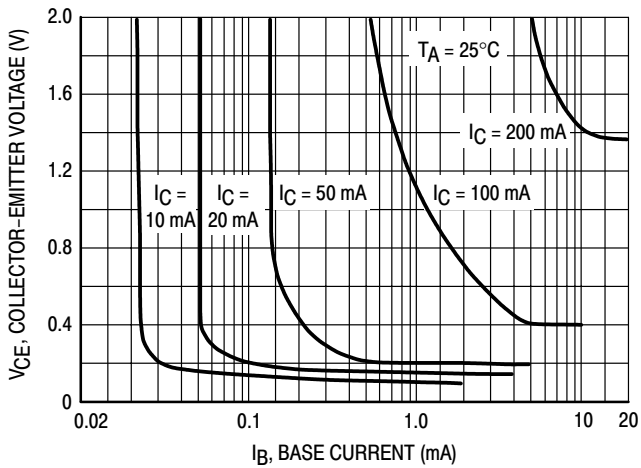


Figure 15. Collector Saturation Region

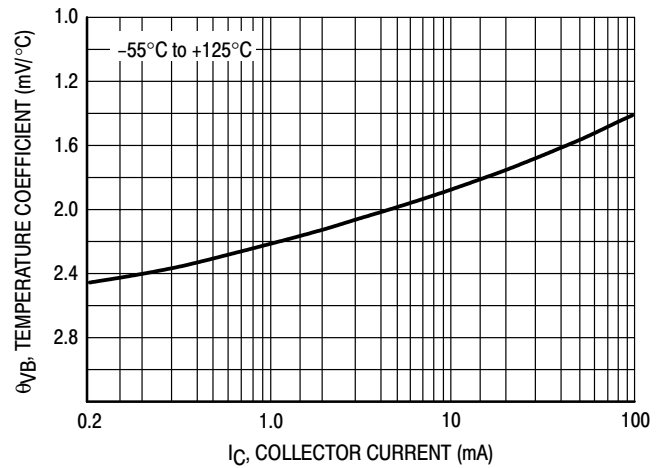


Figure 16. Base-Emitter Temperature Coefficient

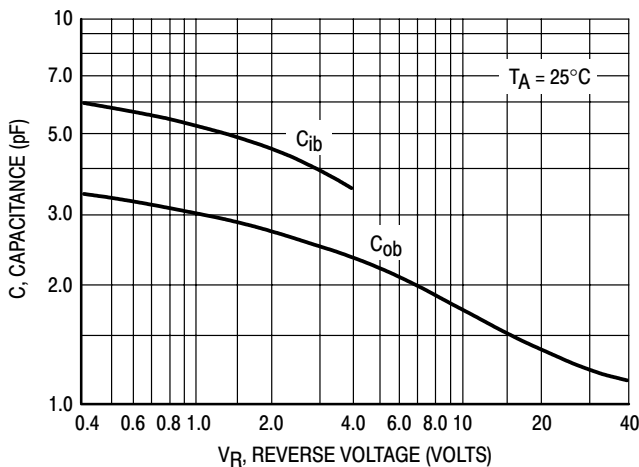


Figure 17. Capacitances

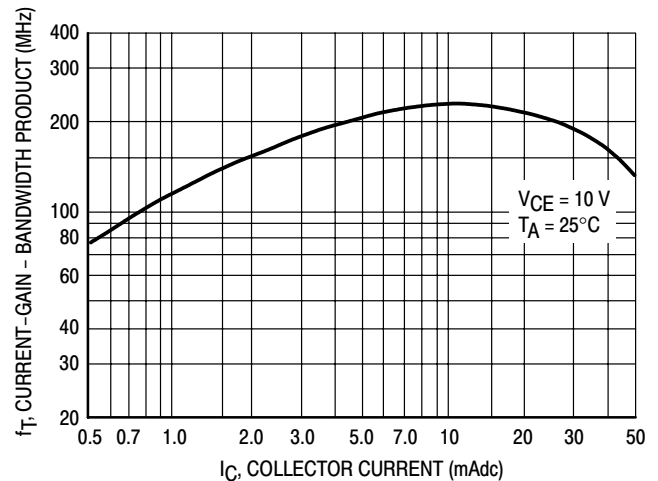


Figure 18. Current-Gain - Bandwidth Product

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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TYPICAL PNP CHARACTERISTICS — LBC847 SERIES & LBC848 SERIES

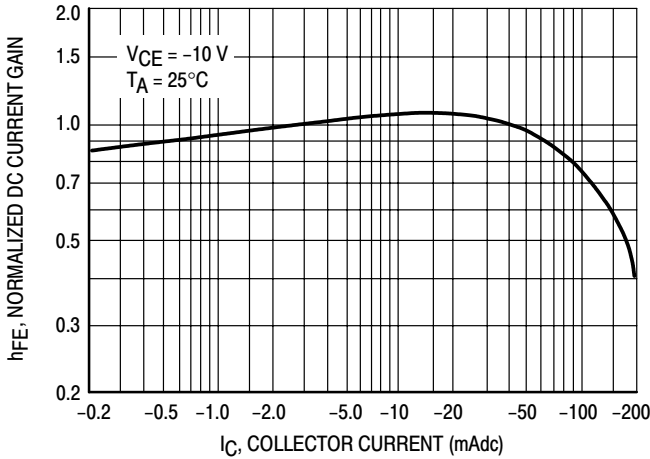


Figure 19. Normalized DC Current Gain

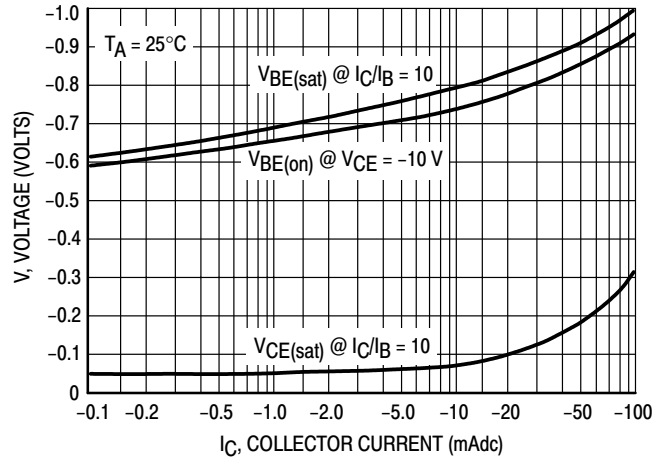


Figure 20. "Saturation" and "On" Voltages

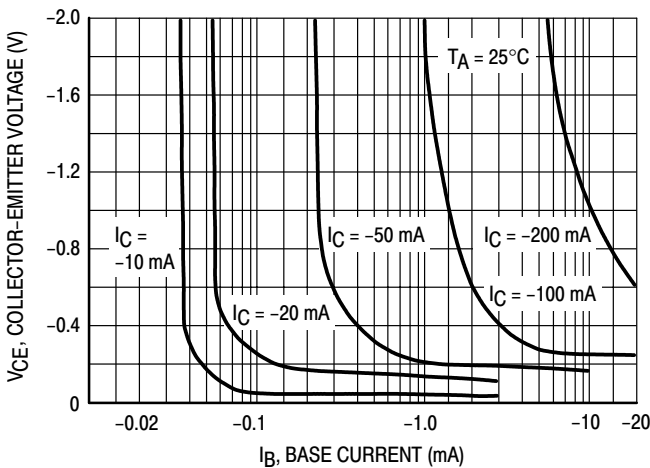


Figure 21. Collector Saturation Region

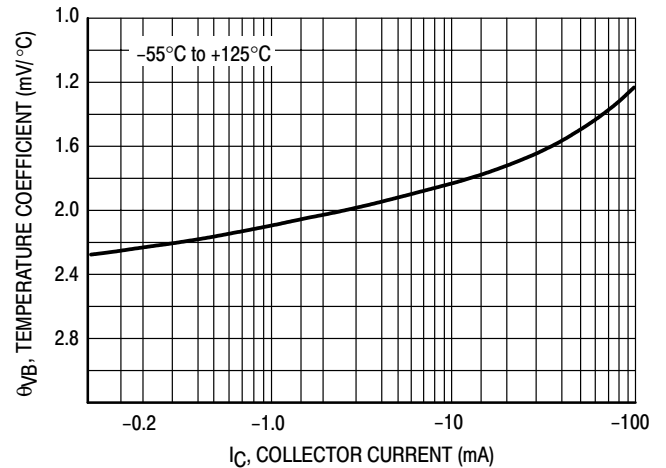


Figure 22. Base-Emitter Temperature Coefficient

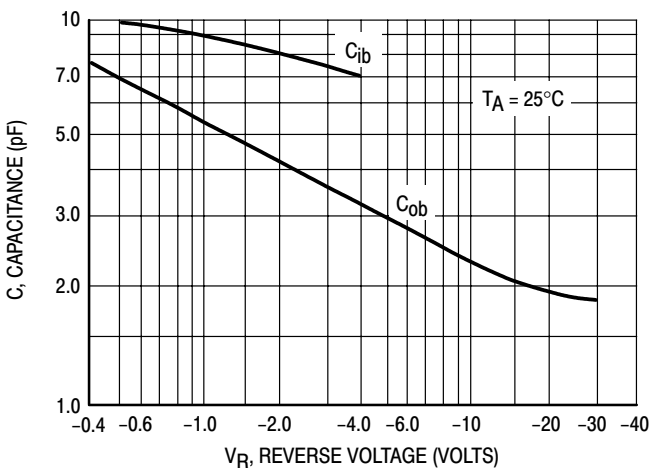


Figure 23. Capacitances

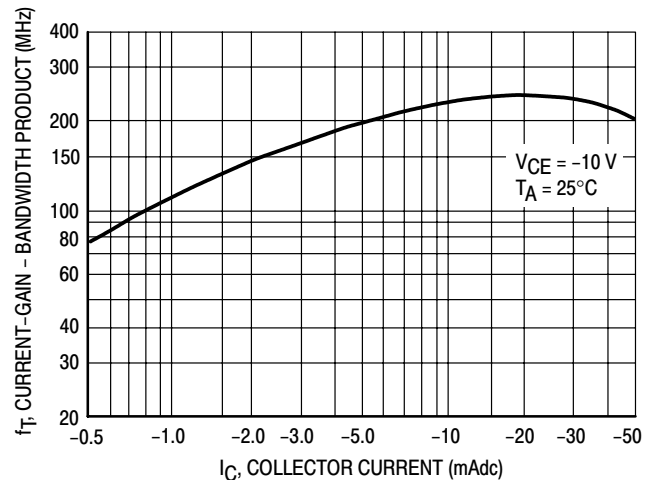


Figure 24. Current-Gain - Bandwidth Product

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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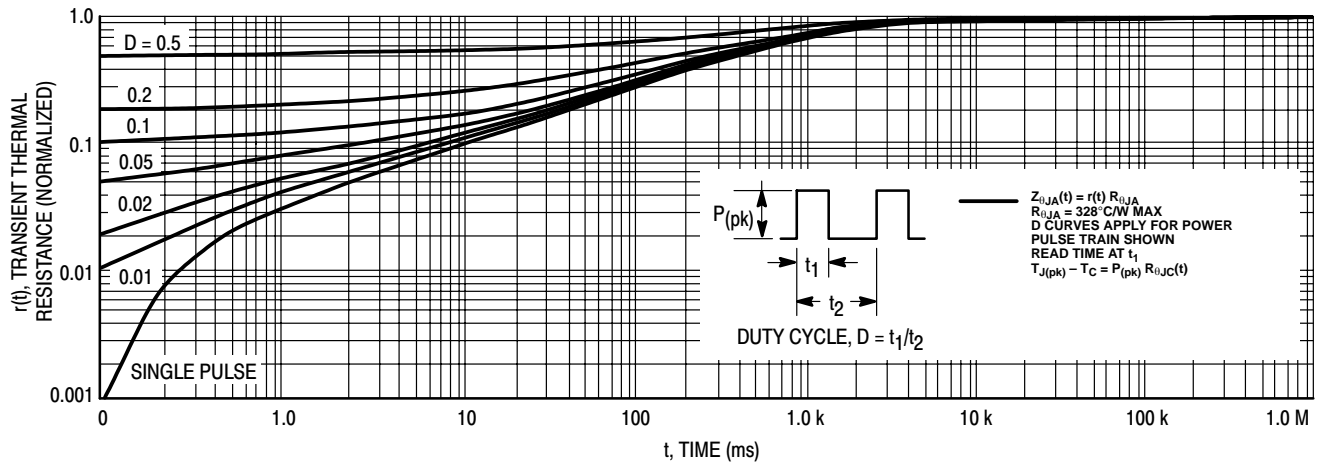
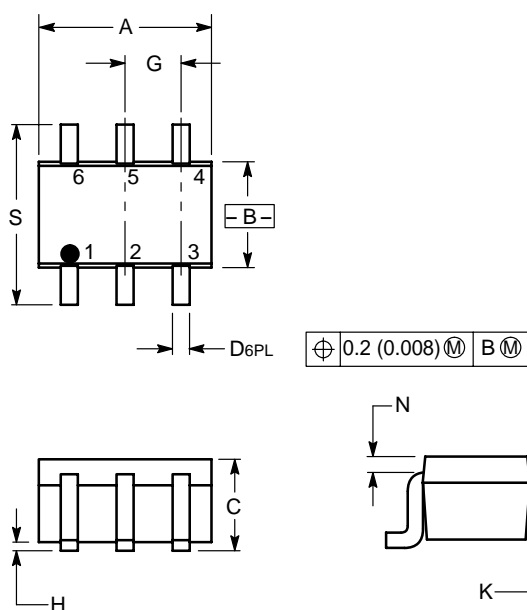


Figure 25. Thermal Response

LBC846BPDW1T1, LBC847BPDW1T1 Series, LBC848BPDW1T1 Series

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SC-88/SOT-363



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

- PIN 1. EMITTER 2
- 2. BASE 2
- 3. COLLECTOR 1
- 4. EMITTER 1
- 5. BASE 1
- 6. COLLECTOR 2

